



N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	
60	0.16 at V _{GS} = 10 V	2.0	
	0.22 at V _{GS} = 4.5 V	1.7	

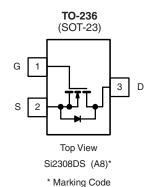
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested



RoHS*

FREE Available



Ordering Information: Si2308DS-T1

Si2308DS-T1-E3 (Lead (Pb)-free)

Si2308DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS}	± 20	¬	
O-ations Date O-mark (T., 450.00)8	T _A = 25 °C		2.0		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	I _D	1.6		
Pulsed Drain Current ^b		I _{DM}	10	A	
Continuous Source Current (Diode Conduction) ^a		I _S	1.0		
M : D D: : :: 3	T _A = 25 °C	P _D	1.25	W	
Maximum Power Dissipation ^a	T _A = 70 °C	LD	0.80	7 vv	
Operating Junction and Storage Temperature Range	ge	T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Unit	
Maximum Junction-to-Ambient ^a	B	100	°C/W	
Maximum Junction-to-Ambient ^c	- R _{thJA}	166	C/VV	

Notes:

- a. Surface Mounted on FR4 board, $t \le 5 \text{ s.}$
- b. Pulse width limited by maximum junction temperature.
- c. Surface Mounted on FR4 board.

For SPICE model information via the Worldwide Web: www.vishay.com/www/product/spice.htm

* Pb containing terminations are not RoHS compliant, exemptions may apply.

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MOSFET SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$	60			v		
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.5		3.0			
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zava Cata Valtaga Dvain Curvant	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V			0.5			
Zero Gate Voltage Drain Current		V _{DS} = 60 V, V _{GS} = 0 V, T _J = 55 °C			10	μΑ		
On-State Drain Current ^a		$V_{DS} \ge 4.5 \text{ V}, V_{GS} = 10 \text{ V}$	6			^		
	I _{D(on)}	$V_{DS} \ge 4.5 \text{ V}, V_{GS} = 4.5 \text{ V}$	4			Α		
		V _{GS} = 10 V, I _D = 2.0 A		0.125	0.16	Ω		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 1.7 \text{ A}$		0.155	0.22			
Forward Transconductance ^a	g _{fs}	$V_{DS} = 4.5 \text{ V}, I_{D} = 2.0 \text{ A}$		4.6		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 1 A, V _{GS} = 0 V		0.77	1.2	V		
Dynamic	<u>'</u>				<u>'</u>			
Total Gate Charge	Q_g			4.8	10			
Gate-Source Charge	Q_{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 2.0 \text{ A}$		0.8		nC		
Gate-Drain Charge	Q_{gd}			1.0				
Gate Resistance	R_g		0.5		3.3	Ω		
Input Capacitance	C _{iss}			240				
Output Capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		50		pF		
Reverse Transfer Capacitance	C _{rss}			15				
Switching								
Turn-On Delay Time	t _{d(on)}			7	15			
Rise Time	t _r	$V_{DD} = 30 \text{ V}, \text{ R}_L = 30 \Omega$ $I_D \cong 1 \text{ A}, \text{ V}_{GEN} = 4.5 \text{ V}, \text{ R}_g = 6 \Omega$		10	20	ns		
Turn-Off Delay Time	t _{d(off)}			17	35			
Fall Time	t _f			6	15			

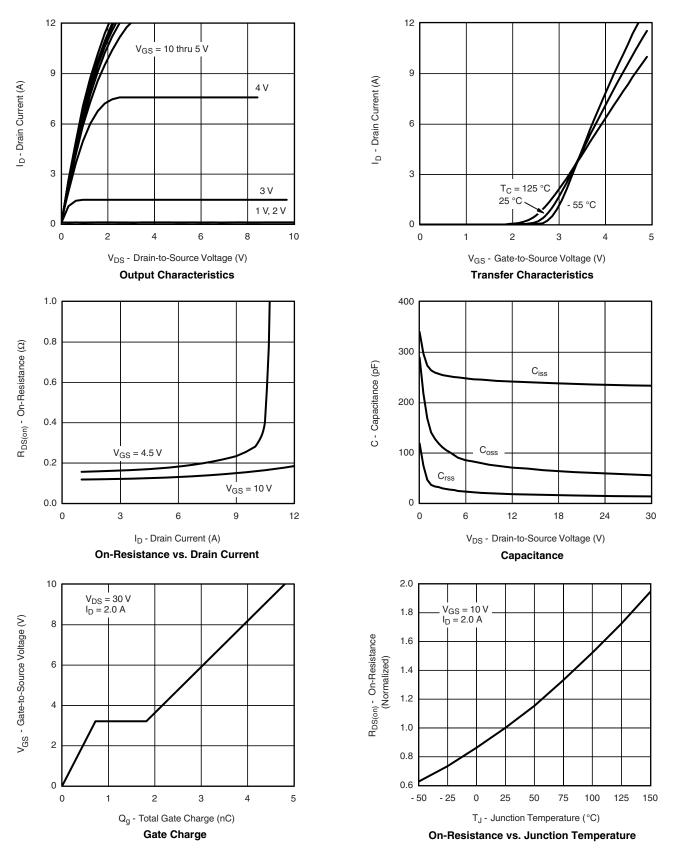
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$



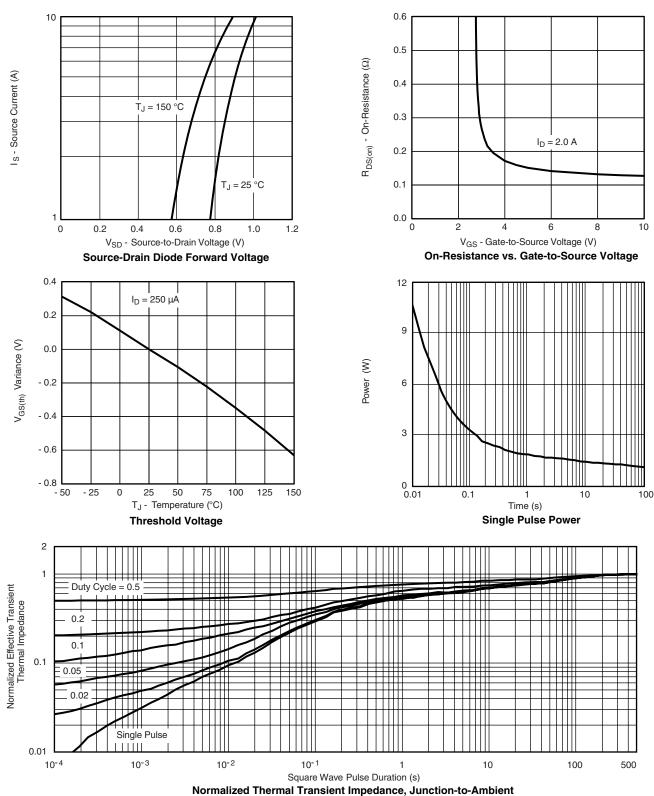
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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